

Growing Demand for Gallium Nitride Devices in Consumer Electronics Drives the Global Market

Growing demand for gallium nitride devices in consumer electronics is one of the significant factors influencing the market growth.

VANCOUVER, B.C, CANADA, June 15, 2023 /EINPresswire.com/ -- The global gallium nitride market is projected to be worth USD 320.4 Million by 2027, according to a current analysis by Emergen Research. The gallium nitride (GaN) market has witnessed substantial growth in recent years due to its wide range of applications across various industries.



Gallium nitride is a compound semiconductor material known for its superior performance characteristics compared to traditional silicon-based semiconductors. With high electron



Gallium Nitride Market Size

– USD 69.3 Million in 2019,
Market Growth - CAGR of
20.8%, Market Trends

–Growing adoption of
electric vehicles"

Emergen Research

mobility, excellent thermal conductivity, and high breakdown voltage, GaN is well-suited for high-power and high-frequency applications. The GaN market has found significant adoption in power electronics, radio frequency (RF) devices, optoelectronics, and other sectors.

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A major driver of the gallium nitride market is the increasing demand for energy-efficient devices and systems. GaN-based power electronics have shown remarkable efficiency improvements, leading to significant energy savings in various applications like electric vehicles, renewable energy systems, and data centers. GaN's favorable characteristics, such as low conduction and

switching losses, make it an attractive alternative to silicon-based power devices, driving market growth.

Telecommunications is another driving force behind the gallium nitride market. The rising need for high-speed data transmission and wireless communication has led to the development of GaN-based RF devices, including power amplifiers. These devices offer higher power density, improved linearity, and enhanced thermal performance compared to conventional RF devices. As a result, GaN has gained traction in the telecommunications industry, further propelling market growth.

Key Parameters Analyzed in This Section:
Company Profiles
Gross Revenue
Profit margins
Product sales trends
Product pricing
Industry Analysis
Sales & distribution channels
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Competitive Landscape:

Furthermore, the report includes an in-depth analysis of the competitive landscape. The segment covers a comprehensive overview of the company profiles along with product profiles, production capacities, products/services, pricing analysis, profit margins, and manufacturing process developments. The report also covers strategic business measures undertaken by the companies to gain substantial market share. The report provides insightful information about recent mergers and acquisitions, product launches, collaborations, joint ventures, partnerships, agreements, and government deals.

Some major companies in the global market report include:

DOWA Electronics Materials Co. Ltd., Cree Inc., American Elements, Furukawa Co. Ltd., Mitsubishi Chemical Corporation, Kyma Technologies Inc., Soitec, IQE PLC, Infineon Technologies, and Nitride Semiconductors Co. Ltd., among others.

Some Key Highlights from the Report

In September 2019, Mitsubishi Electric Corporation declared the development of GaN-HEMT in a multi-cell structure in partnership with the National Institute of Advanced Industrial Science and Technology (AIST) and Research Center for Ubiquitous MEMS and Micro Engineering. The transistor is attached directly to a high thermal conductivity single-crystal heat-dissipating diamond substrate.

Gallium nitride finds application in smaller electronics, high-performance EVs and is the primary material for modern-day LED lighting solutions.

Gallium nitride is of immense significance in photovoltaic cells by enabling them to realize much higher power density than the silicon-based photovoltaic cell.

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Emergen Research has segmented the global gallium nitride market on the basis of substrate type, distribution channel, application, and region:

Substrate Type Outlook (Revenue, USD Billion; 2017-2027)

GaN-on-SiC

GaN-on-Sapphire

Others

Distribution Channel Outlook (Revenue, USD Billion; 2017-2027)

Online

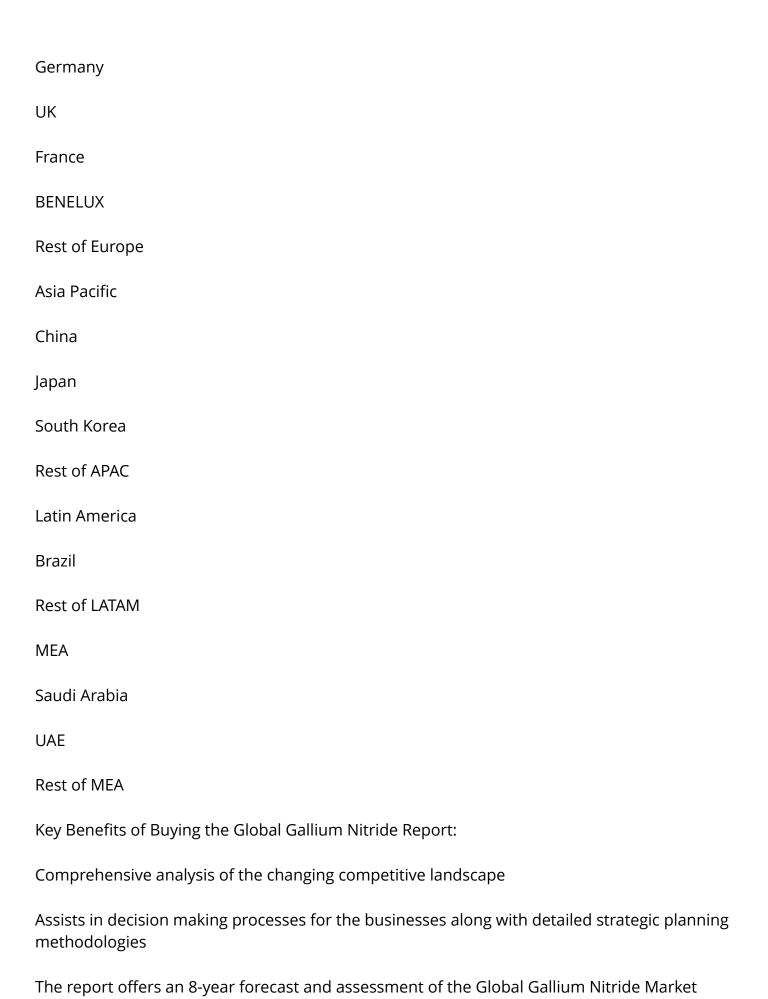
Offline

Application Outlook (Revenue, USD Billion; 2017-2027)

Wireless Infrastructure

Radio Frequency Devices

Satellite Communication
Military & Defense
Others
Power Electronics
Power Supply
Electric Vehicle
LiDAR
Servers & Data Centers
Wireless Power
Solar Photovoltaic Technology
Envelope Tracking
Others
Optoelectronics
LED
LASER
Others
Regional Outlook (Revenue, USD Billion; 2017-2027)
North America
U.S.
Canada
Mexico
Europe



Helps in understanding the key product segments and their estimated growth rate

In-depth analysis of market drivers, restraints, trends, and opportunities

Comprehensive regional analysis of the Global Gallium Nitride Market

Extensive profiling of the key stakeholders of the business sphere

Detailed analysis of the factors influencing the growth of the Global Gallium Nitride Market

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